

#11/B (NE)
Hawkins
12/10/02
PATENT APPLICATIONRESPONSE UNDER 37 CFR §1.116
EXPEDITED PROCEDURE
TECHNOLOGY CENTER ART UNIT 2834

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Toshinari MURAI et al.

Group Art Unit: 2834

Application No.: 09/865,574

Examiner: M. Budd

Filed: May 29, 2001

Docket No.: 109605

For: PIEZOELECTRIC OXIDE SINGLE CRYSTAL WAFER

AMENDMENT AFTER FINAL REJECTION UNDER 37 CFR §1.116Director of the U.S. Patent and Trademark Office
Washington, D.C. 20231

Sir:

In reply to the May 15, 2002 Office Action, the period for response being extended by the attached Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 3 and 4 without prejudice to or disclaimer of the subject matter contained therein.

Please replace claim 1 as follows:

1. (Amended) A piezoelectric oxide single crystal wafer, wherein metal electrodes having a width of 1 μm or less are to be formed on a surface of the wafer, and a number of particles adhering to the surface of the wafer and having a size of 1 μm or more is 85 or less per mm^2 .

REMARKS

Claims 1 and 2 are pending. By this Amendment, claims 3 and 4 are canceled without prejudice or disclaimer, and claim 1 is amended. Reconsideration based on the above amendments and following remarks is respectfully requested.